CMD263P3

5-11 GHz Low Noise Amplifier

Product Overview

The CMD263P3 is a broadband MMIC low noise amplifier housed in a leadless 3x3 mm plastic surface mount QFN package. The CMD263P3 is ideally suited for microwave radios and C and X-band applications where small size and low power consumption are needed. The broadband device delivers greater than 22 dB of gain with a corresponding output 1 dB compression point of +11 dBm and a noise figure of 1.4 dB. The CMD263P3 is a 50 ohm matched design eliminating the need for external DC blocks and RF port matching.

Functional Block Diagram





Key Features

- Ultra Low Noise Figure
- Low Current Consumption
- High Gain Broadband Performance
- Single Supply Voltage: +3.6 V @ 32 mA
- Pb-Free RoHs Compliant 3x3 QFN Package

Ordering Information

Part No.	Description
CMD263P3	100 pcs on 7" reel

Electrical Performance (V_{dd} = 3.6 V, T_A = 25°C, F = 8 GHz)

Parameter	Min	Тур	Max	Units
Frequency Range		5 - 11		GHz
Gain		22		dB
Noise Figure		1.4		dB
Input Return Loss		17		dB
Output Return Loss		13		dB
Output P1dB		11		dBm
Supply Current		32		mA

Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, V _{dd}	5.0 V
RF Input Power	+20 dBm
Channel Temperature, Tch	150°C
Power Dissipation, Pdiss	367 mW
Thermal Resistance, QJC	177° C/W
Operating Temperature	-40 to 85°C
Storage Temperature	-55 to 150°C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Recommended Operating Conditions

Parameter	Min	Тур	Max	Units
V _{dd}	2.0	3.6	4.5	V
l _{dd}		32		mA

Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications (V_{dd} = 3.6 V, T_A = 25°C)

Parameter	Min	Тур	Max	Min	Тур	Max	Units
Frequency Range		5 - 8.5			8.5 - 11		GHz
Gain	19	22	26	19	22	26	dB
Noise Figure		1.6	2.4		1.3	1.7	dB
Input Return Loss		10			10		dB
Output Return Loss		13			12		dB
Output P1dB		11			11.5		dBm
Output IP3		21			21		dBm
Supply Current	22	32	42	22	32	42	mA
Gain Temperature Coefficient		0.013			0.013		dB/°C
Noise Figure Temperature Coefficient		0.008			0.008		dB/°C



Typical Performance



Broadband Performance, V_{dd} = 3.6 V, I_{dd} = 32 mA, T_A = 25° C







Typical Performance







Gain vs. Temperature, V_{dd} = 3.6 V



Typical Performance

- P1dB - Psat Response/dBm Frequency/GHz





Frequency/GHz



Typical Performance



CMD263P3 5-11 GHz Low Noise Amplifier

Mechanical Information

Package Information and Dimensions



CVM DOL C	DIMENSIONS IN MILLIMETERS					
SIMBOLS	MIN	NOM	MAX			
А	0.80	0.90	1.00			
A1	0	0.02	0.05			
A3		0.25REF.				
b	0.18	0.23	0.30			
D	2.85	3.00	3.15			
D1		1.5BSC				
Е	2.85	3.00	3.15			
E1		1.5BSC				
e		0.50BSC				
L	0.30	0.40	0.50			
θ	0		12			
aaa		0.25				
bbb		0.10				
ccc		0.10				
М			0.05			

Notes:

- 1. Dimensions are in millimeters
- 2. RoHS compliant mold compound
- 3. Lead frame material: Copper alloy
- 4. Lead finish: Electroless nickel electroless palladium
- 5. Immersion gold (ENEPIG) plating in accordance with IPC 4556
- 6. Indicated dimension/tolerance applies to leads and exposed pads

Recommended PCB Land Pattern

Qorvo recommends that the user develop the land pattern that will provide the best design for proper solder reflow and device attach for their specific application. Please review Qorvo Application Note AN 105 for a recommended land pattern approach.

Recommended Solder Reflow Profile

Qorvo recommends screen printing with belt furnace reflow to ensure proper solder reflow and device attach. Please review Qorvo Application Note AN 102 for a recommended solder reflow profile.

CMD263P3 5-11 GHz Low Noise Amplifier

Pin Description

Pin Diagram



Functional Description

Pin	Function	Description	Schematic
1, 4 - 9, 12, 13, 15, 16	N/C	No connection required These pins may be connected to RF / DC ground	
2	RF in	DC blocked and 50 ohm matched	RF in O
3, 10, and die paddle	Ground	Connect to RF / DC ground	GND =
11	RF out	DC blocked and 50 ohm matched	RF out
14	V _{dd}	Power supply voltage Decoupling and bypass caps required	Vdd =



Applications Information

Application Circuit



Biasing and Operation

The CMD263P3 is biased with a single positive drain supply. Performance is optimized when the drain voltage is set to +3.6 V, though it may be set to a minimum of +2.0 V and a maximum of +4.5 V.

RF power can be applied at any time.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



Applications Information

Evaluation Board

The circuit board shown has been developed for optimized assembly at Qorvo. A sufficient number of via holes should be used to connect the top and bottom ground planes. As surface mount processes vary, careful process development is recommended.





Bill of Material

Designator	Value	Description			
J1, J2		SMA End Launch Connector			
P1		6 Pin Header			
C1	0.33 µF	Capacitor, Tantalum			
C2	1000 pF	Capacitor, 0603			
C3	100 pF	Capacitor, 0402			
U1		CMD263P3 Low Noise Amplifier			
PCB		CM1074A Evaluation PCB			

CMD263P3 5-11 GHz Low Noise Amplifier

Handling Precautions

Parameter	Rating	Standard	
ESD-Human Body Model (HBM)	Class 1A	ESDA/JEDEC JS-001-2012	Caution!
MSL-Moisture Sensitivity Level	Level 1	IPC/JEDEC J-STD-020	ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C15H12Br402) Free
- SVHC Free
- PFOS Free
- Halogen Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

Important Notice

The information contained in this Data Sheet and any associated documents ("Data Sheet Information") is believed to be reliable; however, Qorvo makes no warranties regarding the Data Sheet Information and assumes no responsibility or liability whatsoever for the use of said information. All Data Sheet Information is subject to change without notice. Customers should obtain and verify the latest relevant Data Sheet Information before placing orders for Qorvo[®] products. Data Sheet Information or the use thereof does not grant, explicitly, implicitly or otherwise any rights or licenses to any third party with respect to patents or any other intellectual property whether with regard to such Data Sheet Information itself or anything described by such information.

DATA SHEET INFORMATION DOES NOT CONSTITUTE A WARRANTY WITH RESPECT TO THE PRODUCTS DESCRIBED HEREIN, AND QORVO HEREBY DISCLAIMS ANY AND ALL WARRANTIES WITH RESPECT TO SUCH PRODUCTS WHETHER EXPRESS OR IMPLIED BY LAW, COURSE OF DEALING, COURSE OF PERFORMANCE, USAGE OF TRADE OR OTHERWISE, INCLUDING THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE. Without limiting the generality of the foregoing, Qorvo® products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death. Applications described in the Data Sheet Information are for illustrative purposes only. Customers are responsible for validating that a particular product described in the Data Sheet Information is suitable for use in a particular application.

© 2020 Qorvo US, Inc. All rights reserved. This document is subject to copyright laws in various jurisdictions worldwide and may not be reproduced or distributed, in whole or in part, without the express written consent of Qorvo US, Inc. | QORVO[®] is a registered trademark of Qorvo US, Inc.



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Qorvo: CMD263P3